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ATTENTION: BOX AFTER FINAL
RESPONSE UNDER 37 C.F.R. § 1.116
EXPEDITED PROCEDURE REQUESTED
EXAMINING GROUP 2811

PATENT
Customer No. 22,852
Attorney Docket No. 08038.0024

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)
Noriaki FUKIAGE) Group Art Unit: 2811
Serial No.: 09/657,055) Examiner: H. Vu
Filed: September 7, 2000)
For: SEMICONDUCTOR DEVICE HAVING)
MULTILAYER INTERCONNECTION)
STRUCTURE AND METHOD OF)
MAKING THE SAME)

RECEIVED
NOV 29 2002
TECHNOLOGY CENTER 2800

Assistant Commissioner for Patents
Washington, DC 20231

Sir:

AMENDMENT

In reply to the Final Office Action of August 26, 2002, and pursuant to 37 C.F.R.
§ 1.116, Applicant proposes that this application be amended as follows:

IN THE CLAIMS:

Please cancel claim 14 without prejudice or disclaimer, and amend claims 1, 5,
and 15, as follows:

1. (Twice Amended) A semiconductor device comprising:
- B¹
- an insulator film formed on a substrate;
 - a wiring layer of copper formed proximate the insulator film; and